

Technical Data Data Sheet N0900, Rev. - Green Products

SBR10150CT SCHOTTKY RECTIFIER

Applications:

- Switching power supply
- Converters
- **Free-Wheeling diodes**
- **Reverse battery protection**

Features:

- 150°C T_J operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device •

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E

D1

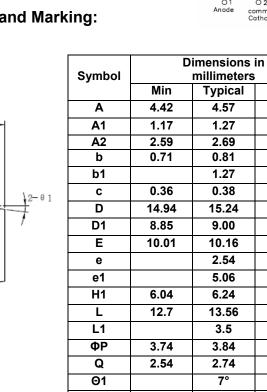
#1 P

3-b1

3-b

- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Mechanical Dimensions (In mm / Inches) and Marking: $2\pi \theta 3$



Typical Max 4.57 4.72 1.27 1.37 2.69 2.89 0.96 0.81 1.27 0.38 0.61 15.24 15.54 9.00 9.15 10.16 10.31 2.54 5.06 6.24 6.44 13.56 13.78 3.5 3.84 4.04 2.74 2.94 7° Θ2 3° Θ3 4°

OPTION1 (HD)

с

 China -Germany http://www.smc-diodes.com
sales@ smc-diodes.com

A2

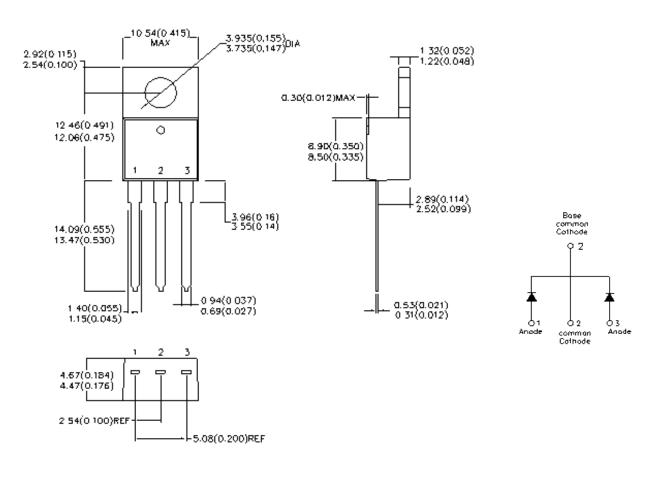
- Korea - Singapore - United States •

2 Base common Cathode Q 2 Ċ 2 33 Anode common Cathode Anode



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OPTION2 (CJ)

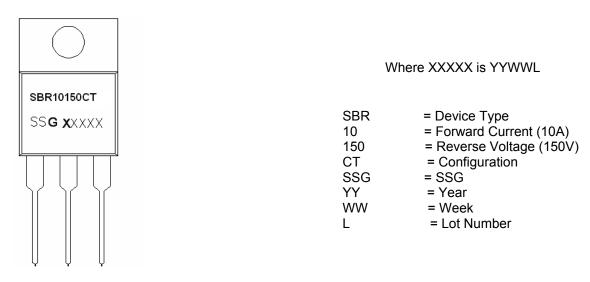
TO-220AB



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Marking Diagram:



Cautions: Molding resin Epoxy resin UL:94V-0

Ordering Information:

Device	Package	Shipping
SBR10150CT	TO-220AB (Pb-Free)	50 pcs / tube

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	V _{RWM}	-	150	V
Average Forward Current (per device)	I _{F(AV)}	50% duty cycle @T _C = 145°C, rectangular wave form	10	A
Peak One Cycle Non-Repetitive Surge Current (per leg)	I _{FSM}	8.3 ms, half Sine pulse	120	A



Electrical Characteristics:

Characteristics	Symbol	Condition	Max.	Units
Forward Voltage Drop (per leg) *	V_{F1}	@ 5 A, Pulse, T _C = 25 °C	0.93	V
Reverse Current (per leg) *	I _{R1}	$@V_R = rated V_R$ T _c = 25 °C	1.0	mA
Repetitive peak reverse current	IRRM	tp = 2 μs square F= 1 kHz	1	A
Junction Capacitance (per leg)	CT	@V _R = 5V, T _C = 25 °C f _{SIG} = 1MHz	200	pF

* Pulse Width < 300µs, Duty Cycle <2%

Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T _{stg}	-	-55 to +150	°C
Maximum Thermal	$R_{ ext{ heta}JC}$	DC operation	4.5	°C/W
Resistance Junction to Case				
Approximate Weight	wt	-	2	g
Case Style	TO-220AB			



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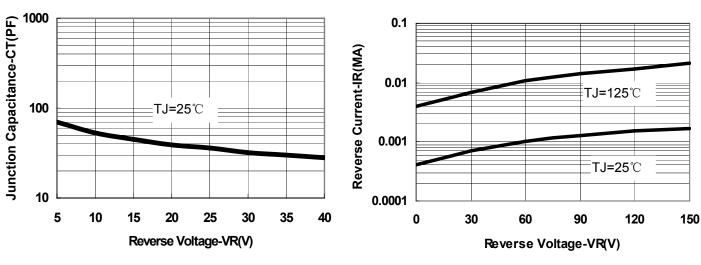


Fig.1-Typical Junction Capacitance

Fig.2-Typical Reverse Characteristics

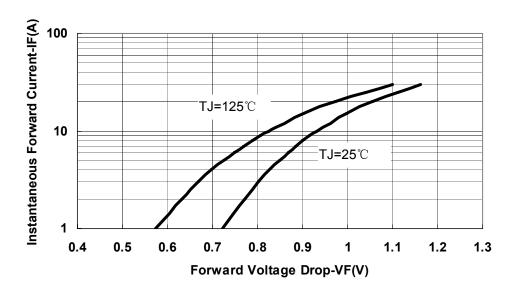


Fig.3-Typical Instantaneous Forward Voltage Characteristics



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SBR10150CT

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